

Refine Search

Search Results -

Terms	Documents
L4 and (("SiC" or "silicon carbide") near10 ("nitrogen environment" OR "nitrogen atmosphere"))	2

Database:

US Pre-Grant Publication Full-Text Database
 US Patents Full-Text Database
 US OCR Full-Text Database
 EPO Abstracts Database
 JPO Abstracts Database
 Derwent World Patents Index
 IBM Technical Disclosure Bulletins

Search:

L6

Refine Search

Recall Text

Clear

Interrupt

Search History

 DATE: Wednesday, June 23, 2004 [Printable Copy](#) [Create Case](#)

<u>Set</u> <u>Name</u>	<u>Query</u>	<u>Hit</u> <u>Count</u>	<u>Set</u> <u>Name</u> result set
<i>DB=USPT; PLUR=YES; OP=OR</i>			
<u>L6</u>	L4 and (("SiC" or "silicon carbide") near10 ("nitrogen environment" OR "nitrogen atmosphere"))	2	<u>L6</u>
<u>L5</u>	L4 and (precursors near10 ("nitrogen environment" OR "nitrogen atmosphere"))	0	<u>L5</u>
<u>L4</u>	L3 and method	137	<u>L4</u>
<u>L3</u>	L2 same ohm-cm	144	<u>L3</u>
<u>L2</u>	("silicon carbide" or SiC) same resistivity	1199	<u>L2</u>
<u>L1</u>	5359219	66	<u>L1</u>

END OF SEARCH HISTORY

Refine Search

Search Results -

Terms	Documents
L13	0

Database:

US Pre-Grant Publication Full-Text Database
 US Patents Full-Text Database
 US OCR Full-Text Database
 EPO Abstracts Database
 JPO Abstracts Database
 Derwent World Patents Index
IBM Technical Disclosure Bulletins

Search:

L14

Refine Search

Recall Text

Clear

Interrupt

Search History

 DATE: Wednesday, June 23, 2004 [Printable Copy](#) [Create Case](#)

<u>Set</u> <u>Name</u>	<u>Query</u>	<u>Hit</u> <u>Count</u>	<u>Set</u> <u>Name</u> result set
side by side			
	<i>DB=TDBD; PLUR=YES; OP=OR</i>		
<u>L14</u>	L13	0	<u>L14</u>
	<i>DB=DWPI; PLUR=YES; OP=OR</i>		
<u>L13</u>	L12	0	<u>L13</u>
	<i>DB=JPAB; PLUR=YES; OP=OR</i>		
<u>L12</u>	L11	0	<u>L12</u>
	<i>DB=EPAB; PLUR=YES; OP=OR</i>		
<u>L11</u>	L10	0	<u>L11</u>
	<i>DB=USOC; PLUR=YES; OP=OR</i>		
<u>L10</u>	L9	0	<u>L10</u>
	<i>DB=PGPB; PLUR=YES; OP=OR</i>		
<u>L9</u>	L8	0	<u>L9</u>
	<i>DB=USPT; PLUR=YES; OP=OR</i>		
<u>L8</u>	L4 and (opaque near7 wavelength)	0	<u>L8</u>

<u>L7</u>	l4 and wavelength	26	<u>L7</u>
<u>L6</u>	L4 and (("SiC" or "silicon carbide") near10 ("nitrogen environment" OR "nitrogen atmosphere"))	2	<u>L6</u>
<u>L5</u>	L4 and (precursors near10 ("nitrogen environment" OR "nitrogen atmosphere"))	0	<u>L5</u>
<u>L4</u>	L3 and method	137	<u>L4</u>
<u>L3</u>	L2 same ohm-cm	144	<u>L3</u>
<u>L2</u>	("silicon carbide" or SiC) same resistivity	1199	<u>L2</u>
<u>L1</u>	5359219	66	<u>L1</u>

END OF SEARCH HISTORY